脳機能模倣素子など次世代微細素子の開発





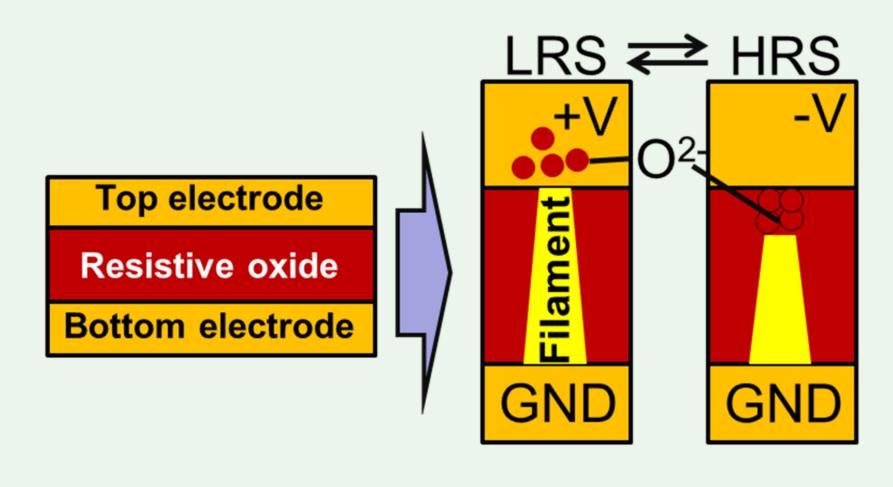


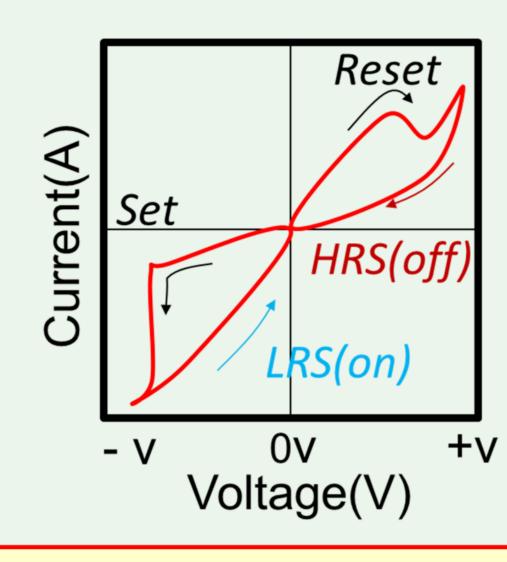


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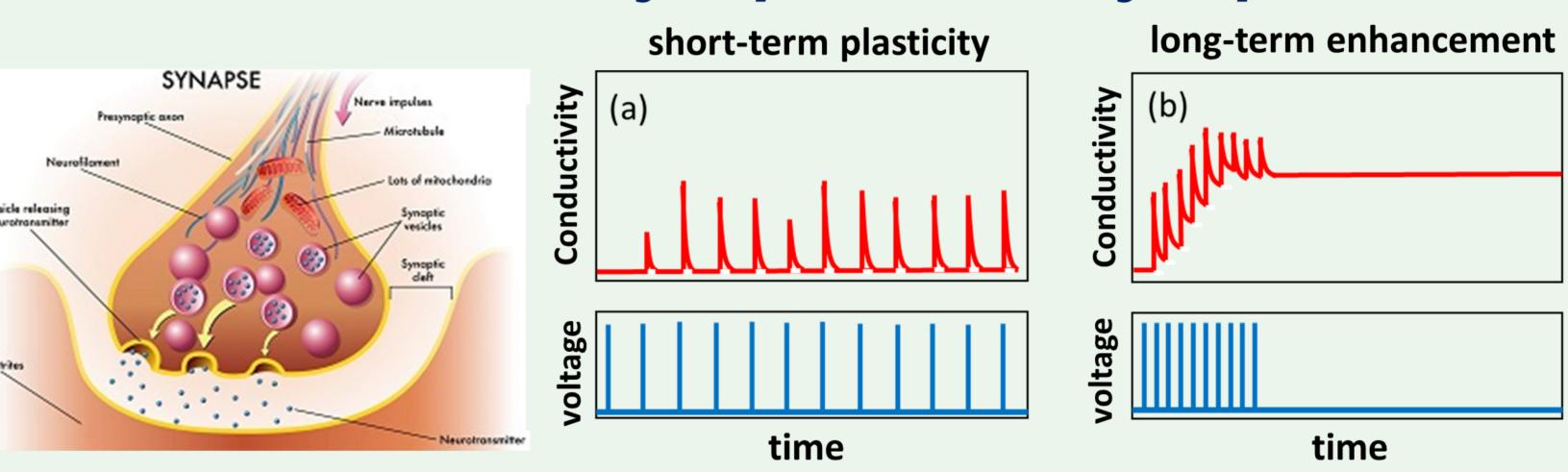
研究分野:半導体デバイス、記憶素子、ナノ粒子、2次元材料

Resistiv Memory





Electrical behavior of synapses and synaptic device



Constituted of metal oxide showing resistance change by voltage application. Formation of filaments by movement of oxide ions.

Low voltage (1~3 V) and High speed operation (<10 nsec)
Scalable

information, demands on memory devices.

Attention to elements and circuits imitating the human brain.

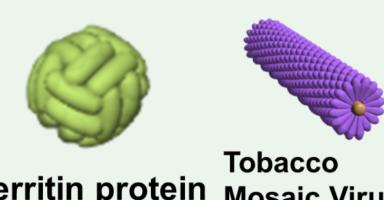
Higher performance driving elements for handling complicated

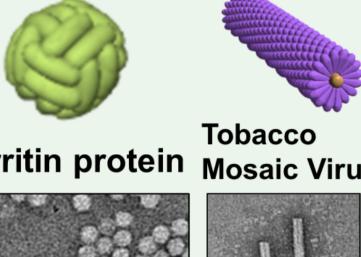
Bio Nano Process (BNP)

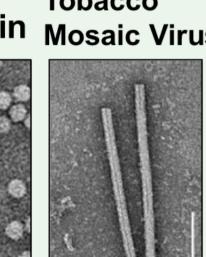
- Promising bottom up process which overcomes the scaling limit of top down process.
- Biological method to produce nano functional structure using biomineralization of the

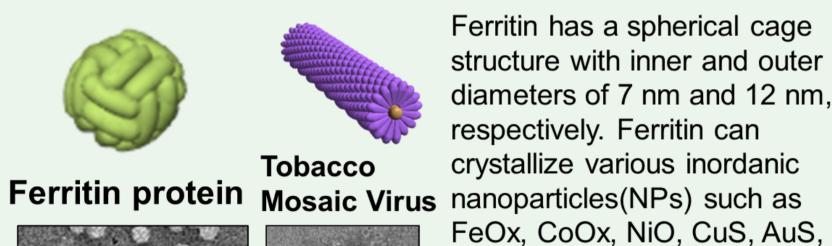
supramolecular protein. Supermolecular protein

Structural uniformity







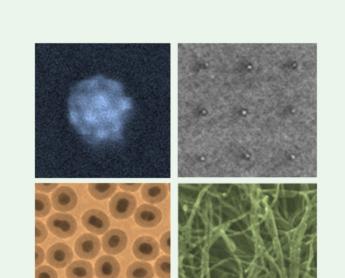


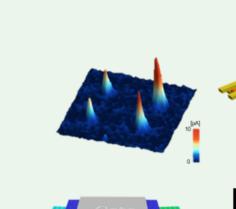
Biomineralization

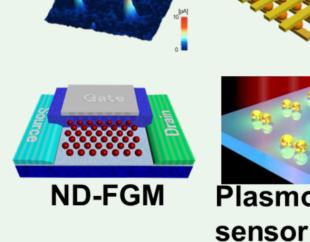
PtS, TaOx. Biomineralization

Nano Structure

 Self-organization Selective adsorption







Solar cell

Bio-sensor

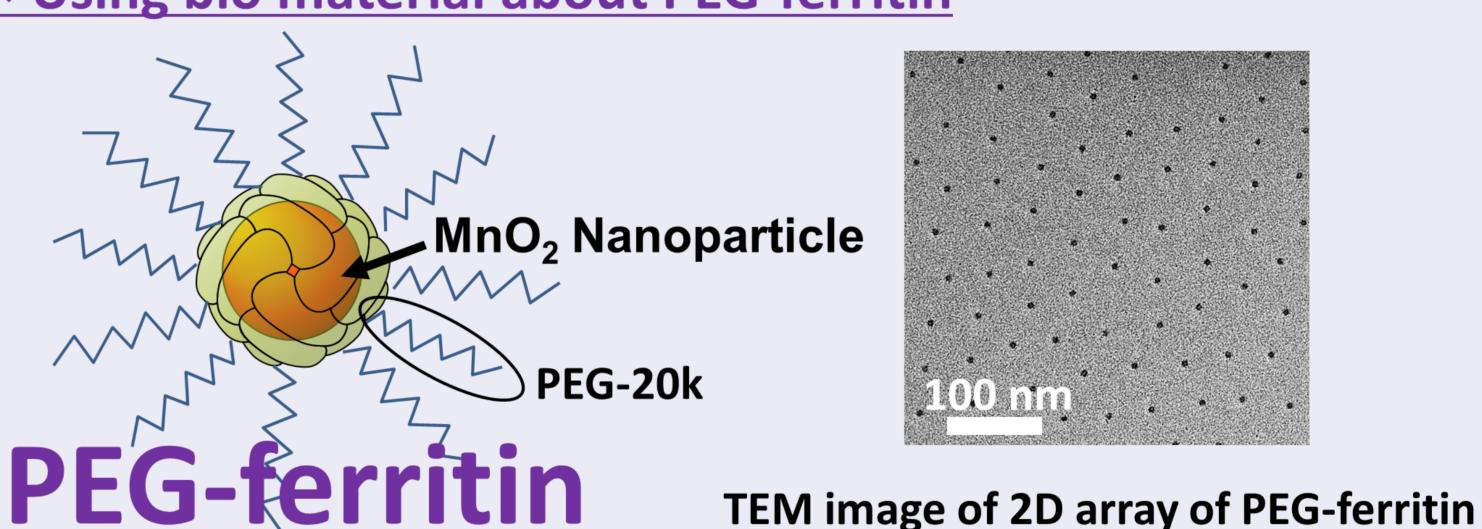
Plasmon

Devices

Memory(FGM, ReRAM)

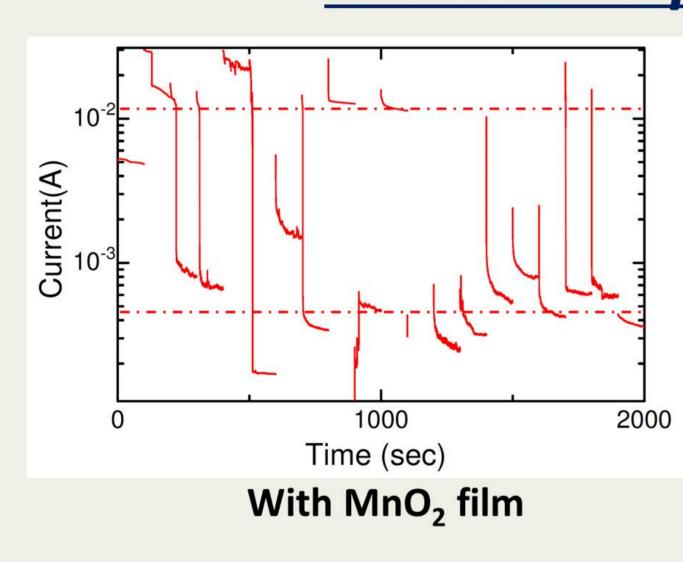
Object

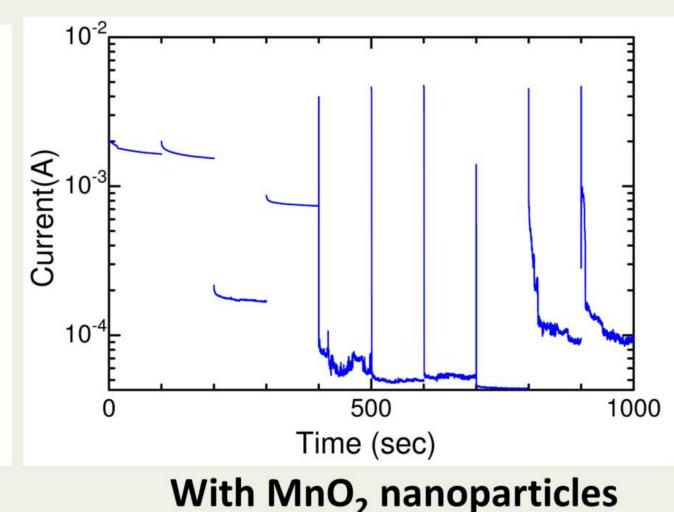
Fabrication of synapse-like device using resistive memory ⇒Using bio material about PEG-ferritin



Results

Electrical characteristics of synaptic device Short-term plasticity



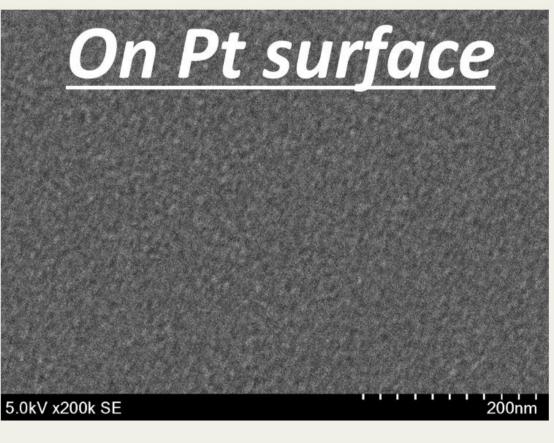


Comparison of devices using MnO₂ film and MnO₂ NPs.

- After applying a pulse of 100 ns width of 5 V, apply a bias of 1 V and observe the current value.
- Immediately after the pulse, it changes to low resistance.
- It changes to high resistance by applying 1 V bias.
- When current flows in MnO₂, it turns into Mn₂O₃ and oxygen is supplied to Ta₂O₅ and reoxidation.
- At 100 s intervals, short-term plasticity was confirmed with both film and nanoparticles.
- long-term film, enhancement can not be seen unless a pulse is applied 500 times at a time.
- For NPs, long-term enhancement was confirmed by applying pulses at 1 second intervals.

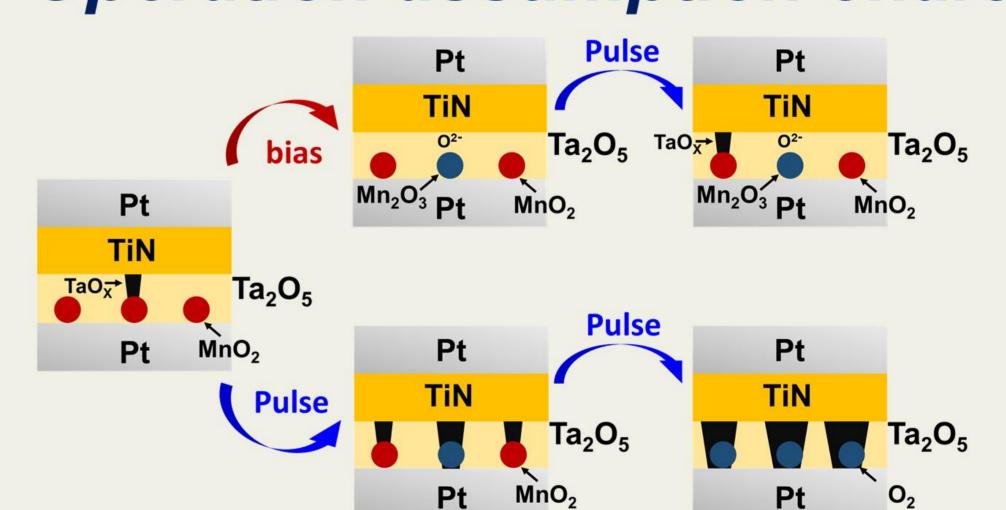
SEM observation of 2D array of MnO₂

On Si surface

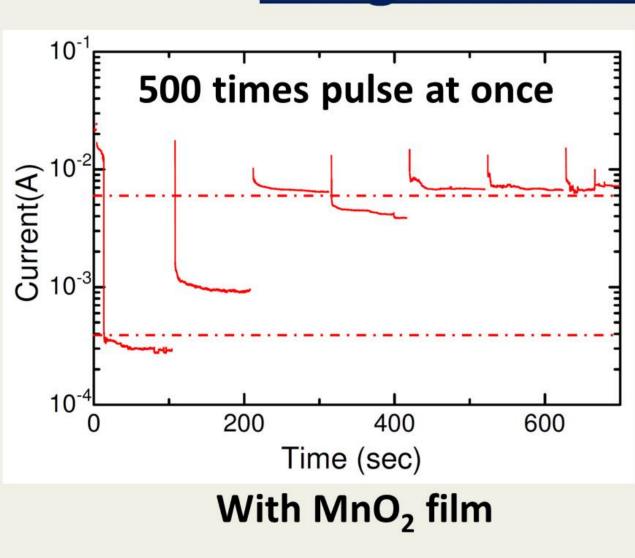


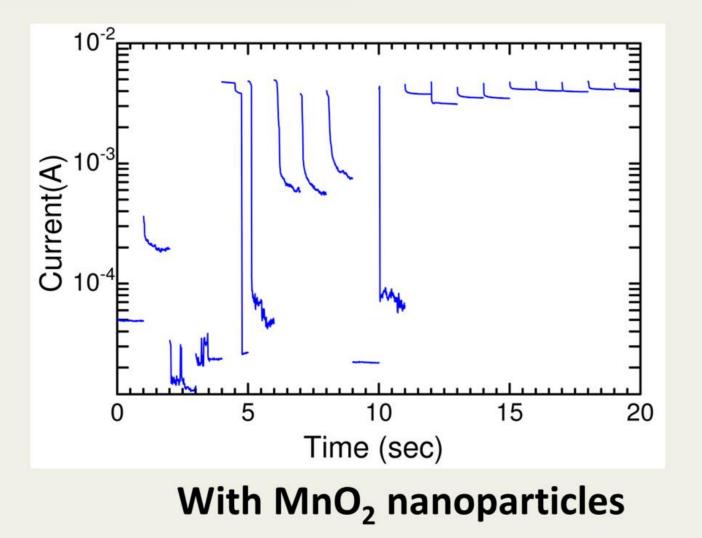
- Confirmed that the NPs are arranged at 50 nm on Si.
- ✓ An electrode with a diameter of 300 μm, there are about 4×10^7 NPs.
- Although it is difficult to confirm on Pt, since it is on the same substrate, NPs might be arranged just like on Si.

Operation assumption chart



Long-term enhancement





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